

SOP8 Plastic-Encapsulate MOSFETS

| $V_{(BR)DSS}$ | $R_{DS(on)TYP}$ | I_D |
|---------------|-------------------------------|-------|
| -30V | <u>9mΩ@-10V</u> 13mΩ@-4.5V | -15A |



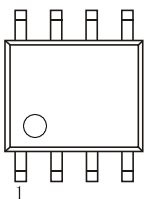
DESCRIPTION

The **JS4407L** combines advanced trench MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is ideal for load switch and battery protection applications

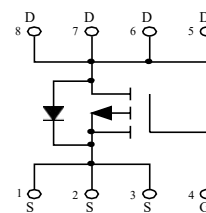
APPLICATIONS

- Battery protection applications
- Load switch

MARKING



Equivalent Circuit



Package Marking and Ordering Information

| Product | Package | Marking | Packing | Min Unit Quantity |
|---------|---------|---------|--------------|-------------------|
| JS4407L | SOP8 | * | 3000PCS/Reel | 3000PCS |

ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|------------------------------|----------|----------------------|
| Drain-Source Voltage | V_{DS} | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 25 | V |
| Continuous Drain Current | I_D ^① | -15 | A |
| Pulsed Drain Current | I_{DM} ^② | -42 | A |
| Single Pulsed Avalanche Energy | E_{AS} ^③ | 107 | mJ |
| Maximum Power Dissipation | P_D ^④ | 3 | W |
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}$ ^⑤ | 41.7 | $^{\circ}\text{C/W}$ |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | -55~+150 | $^{\circ}\text{C}$ |

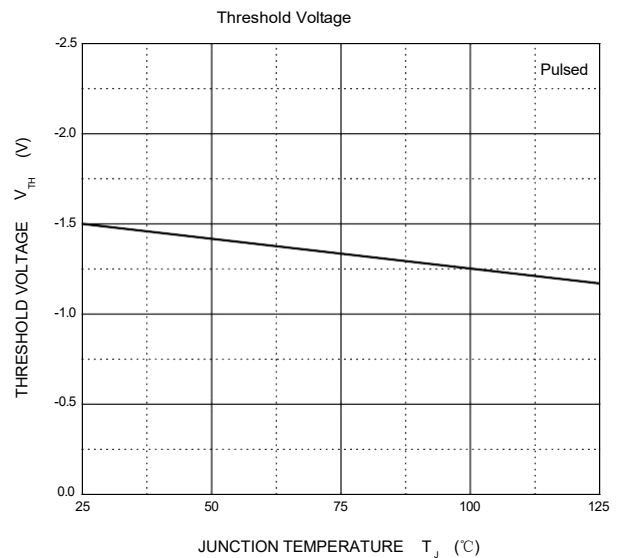
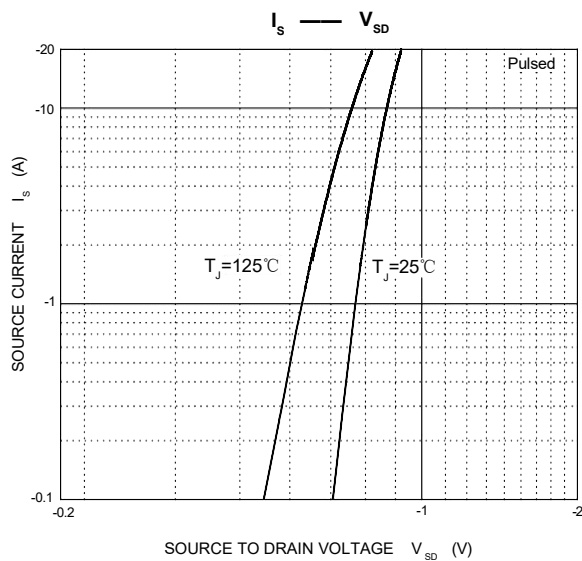
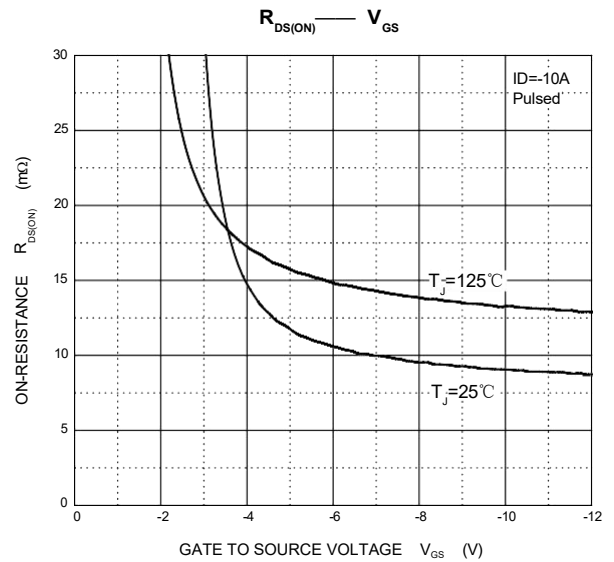
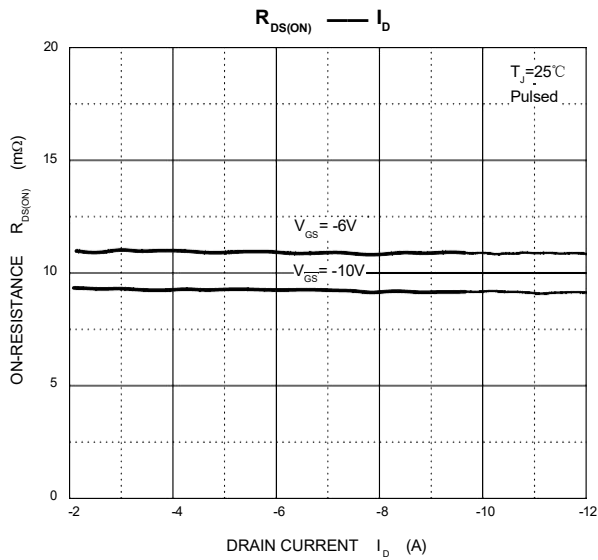
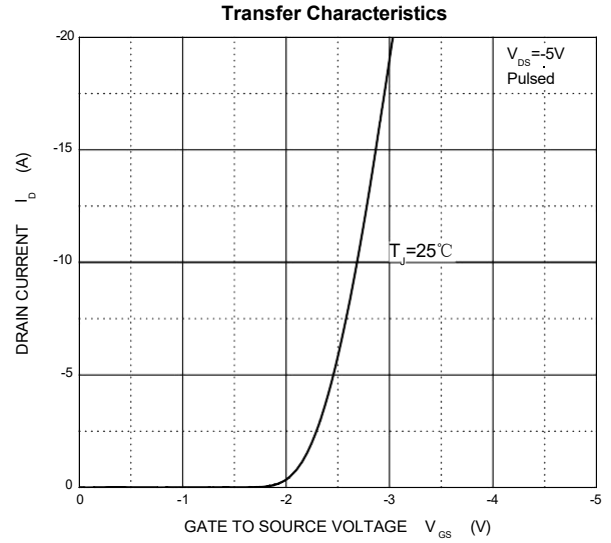
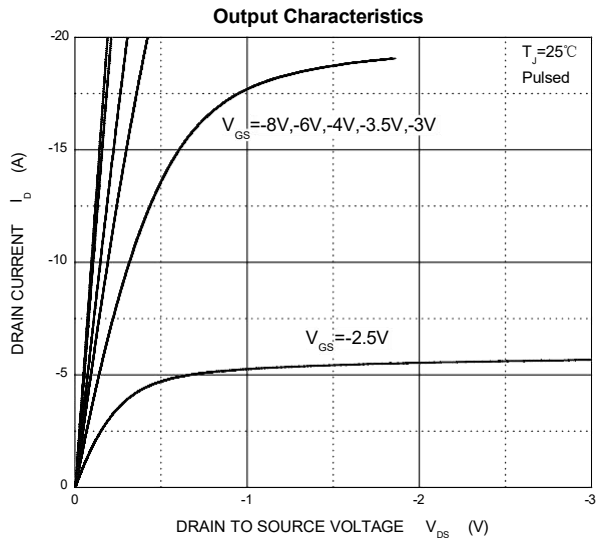
MOSFET ELECTRICAL CHARACTERISTICS
T_a=25 °C unless otherwise specified

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|--|------------------------------|--|------------------------|------|------|------|
| Off characteristics | | | | | | |
| Drain-source breakdown voltage | V _{(BR) DSS} | V _{GS} = 0V, I _D = -250μA | -30 | | | V |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = -24V, V _{GS} = 0V | T _J = 25°C | | -1 | μA |
| | | | T _J = 125°C | | -200 | |
| Gate-body leakage current | I _{GSS} | V _{DS} = 0V, V _{GS} = ±20V | | | ±100 | nA |
| On characteristics^④ | | | | | | |
| Gate-threshold voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = -250μA | -1.0 | -1.5 | -2.2 | V |
| Static drain-source on-state resistance | R _{DS(on)} | V _{GS} = -10V, I _D = -10A | | 9 | 15 | mΩ |
| | | V _{GS} = -4.5V, I _D = -8A | | 13 | 20 | mΩ |
| Forward transconductance | g _{FS} | V _{DS} = -5V, I _D = -10A | 25 | | | S |
| Dynamic characteristics^{④ ⑤} | | | | | | |
| Input capacitance | C _{ISS} | V _{DS} = -15V, V _{GS} = 0V, f = 1MHz | | 2885 | 5770 | pF |
| Output capacitance | C _{OSS} | | | 341 | 682 | |
| Reverse transfer capacitance | C _{RSS} | | | 305 | 610 | |
| Switching characteristics^{④ ⑤} | | | | | | |
| Total gate charge | Q _g | V _{DS} = -15V, V _{GS} = -10V, I _D = -10A | | 48 | 96 | nC |
| Gate-source charge | Q _{gs} | | | 12 | 24 | |
| Gate-drain charge | Q _{gd} | | | 14 | 28 | |
| Turn-on delay time | t _{d(on)} | V _{DS} = -15V, V _{GS} = -10V, R _L = 1.25Ω, R _G = 3Ω | | 16 | | ns |
| Turn-on rise time | t _r | | | 12 | | |
| Turn-off delay time | t _{d(off)} | | | 45 | | |
| Turn-off fall time | t _f | | | 21 | | |
| Drain-Source Diode Characteristics | | | | | | |
| Drain-source diode forward voltage | V _{SD} ^④ | V _{GS} = 0V, I _S = -2A | | | -1.2 | V |
| Continuous drain-source diode forward current | I _S ^① | | | | -11 | A |
| Pulsed drain-source diode forward current | I _{SM} ^② | | | | -42 | A |

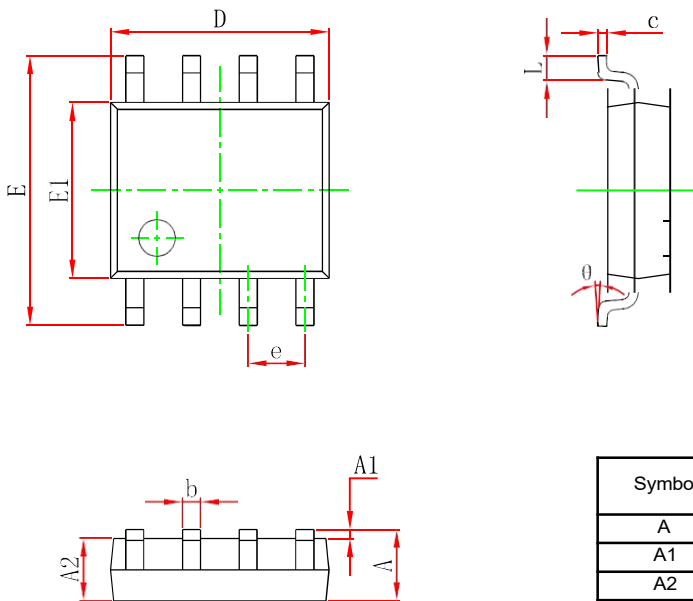
Notes:

- T_C = 25°C Limited only by maximum temperature allowed.
- P_W ≤ 10μs, Duty cycle ≤ 1%.
- EAS condition: V_{DD} = -20V, V_{GS} = -10V, L = 0.5mH, R_G = 25Ω Starting T_J = 25°C.
- Pulse Test : Pulse Width ≤ 300μs, duty cycle ≤ 2%.
- Guaranteed by design, not subject to production.
- The value of R_{θJA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T_a = 25°C, t ≤ 10sec.

Typical Characteristics

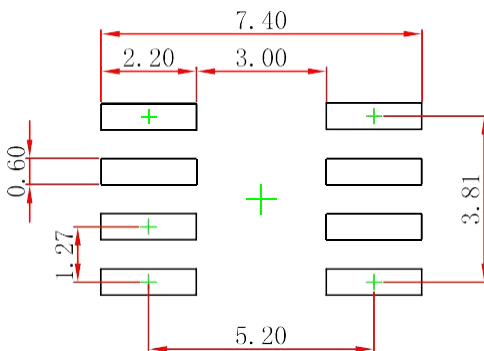


SOP8 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.450 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.007 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.201 |
| e | 1.270 (BSC) | | 0.050 (BSC) | |
| E | 5.800 | 6.200 | 0.228 | 0.244 |
| E1 | 3.800 | 4.000 | 0.150 | 0.157 |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

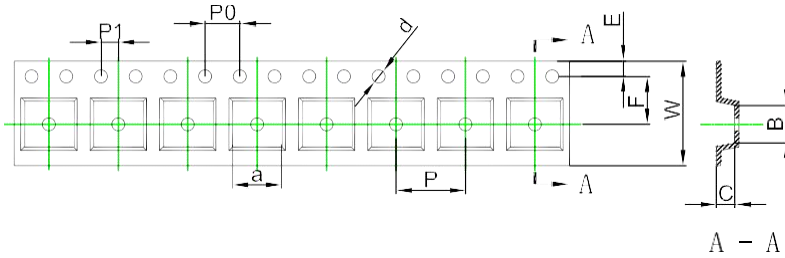
SOP8 Suggested Pad Layout



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.

SOP8 Tape and Reel

SOP8 Embossed Carrier Tape



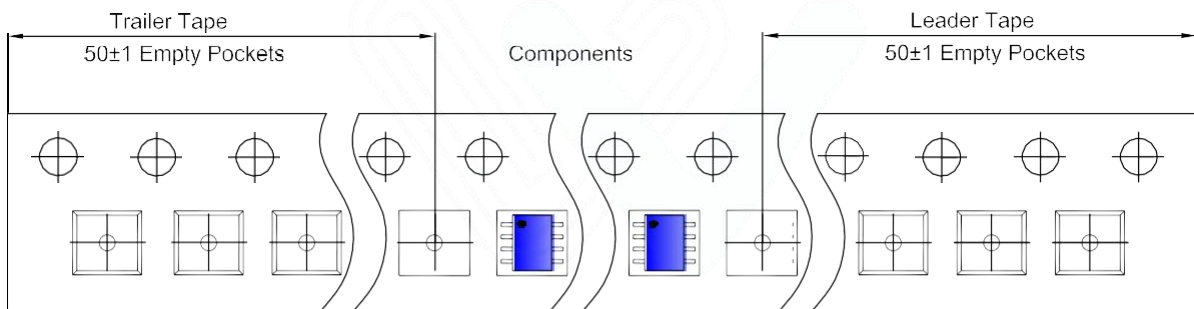
Packaging Description:

SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

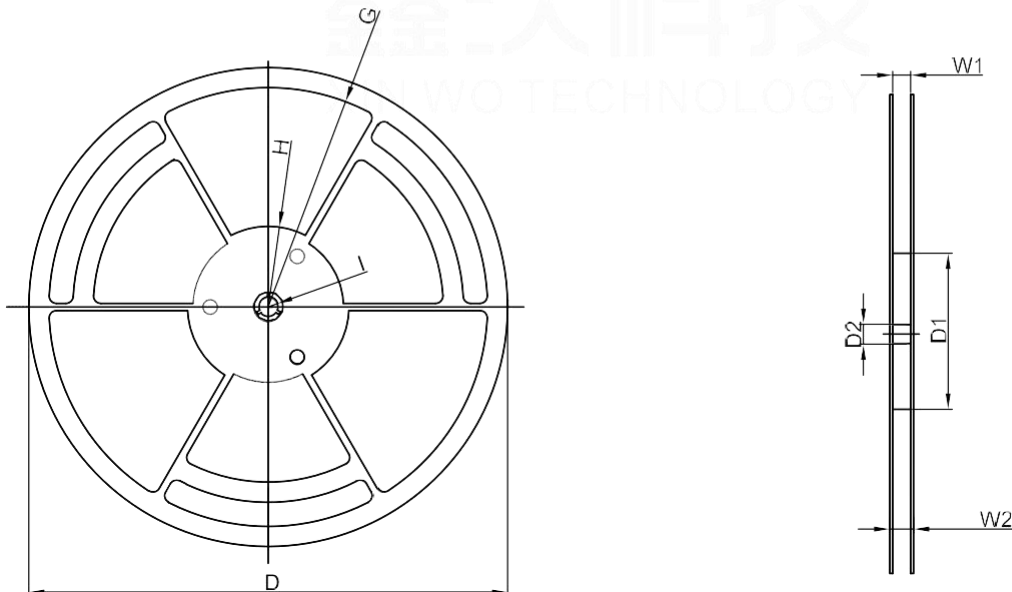
ALL DIM IN mm

| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|------|------|------|-------|------|------|------|------|------|-------|
| Pkg type | a | B | C | d | E | F | P0 | P | P1 | W |
| SOP8 | 6.40 | 5.40 | 2.10 | Ø1.50 | 1.75 | 5.50 | 4.00 | 8.00 | 2.00 | 12.00 |

SOP8 Tape Leader and Trailer



SOP8 Reel



| Dimensions are in millimeter | | | | | | | | |
|------------------------------|---------|--------|-------|---------|--------|-------|-------|-------|
| Reel Option | D | D1 | D2 | G | H | I | W1 | W2 |
| 13" Dia | Ø330.00 | 100.00 | 13.00 | R151.00 | R56.00 | R6.50 | 12.40 | 17.60 |